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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS

DATA SHEET

74LVT240ABT octal inverting buffer (3-State)

Product specification Supersedes data of 1994 May 16 IC23 Data Handbook





3.3V Octal inverting buffer (3-State)

74LVT240

FEATURES

- Octal bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Power-up 3-State
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model.

DESCRIPTION

The LVT240 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is an octal inverting buffer that is ideal for driving bus lines. The device features two Output Enables (1 \overline{OE} , 2 \overline{OE}), each controlling four of the 3-State outputs.

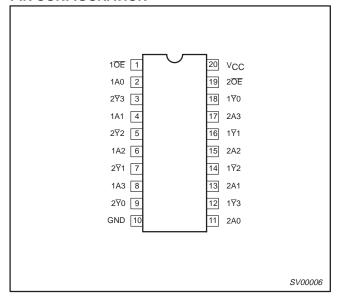
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	$C_L = 50pF;$ $V_{CC} = 3.3V$	2.5 2.6	ns
C _{IN}	Input capacitance	V _I = 0V or 3.0V	4	pF
C _{OUT}	Output capacitance	Outputs disabled; V _O = 0V or 3.0V	8	pF
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} = 3.6V	0.12	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic SOL	-40°C to +85°C	74LVT240 D	74LVT240 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to +85°C	74LVT240 DB	74LVT240 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVT240 PW	74LVT240PW DH	SOT360-1

PIN CONFIGURATION



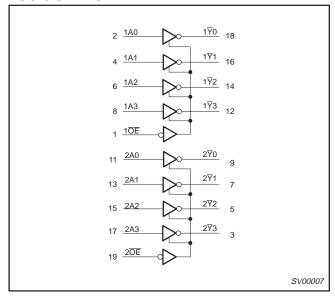
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 4, 6, 8	1A0 – 1A3	Data inputs
11, 13, 15, 17	2A0 – 2A3	Data inputs
18, 16, 14, 12	1₹0 – 1₹3	Data outputs
9, 7, 5, 3	2 7 0 − 2 7 3	Data outputs
1, 19	1 0E , 2 0E	Output enables
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

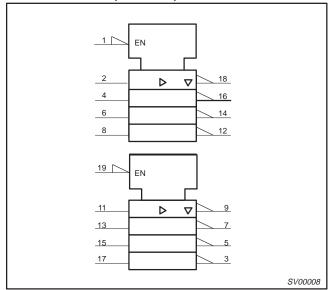
3.3V Octal inverting buffer (3-State)

74LVT240

LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INP	OUTPUTS	
nOE	nAx	n₹x
L	L	Н
L	Н	L
Н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High impedance "Off" state

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT	
V _{CC}	DC supply voltage		-0.5 to +4.6	V	
VI	DC input voltage ³		-0.5 to +7.0	V	
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V	
	DC autout auroat	Output in Low state	128	^	
lout	DC output current	Output in High state	-64	mA	
I _{IK}	DC input diode current	V _I < 0	-50	mA	
I _{OK}	DC output diode current	V _O < 0	-50	mA	
T _{stg}	Storage temperature range		-65 to 150	°C	

NOTES:

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

3.3V Octal inverting buffer (3-State)

74LVT240

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT		
STWIBOL	TANAMETER	MIN	MAX	0.411	
V _{CC}	DC supply voltage	2.7	3.6	V	
V _I	Input voltage	0	5.5	V	
V _{IH}	High-level input voltage	2.0		V	
V _{IL}	Low-level Input voltage		0.8	V	
I _{OH}	High-level output current		-32	mA	
loL	Low-level output current		32	mA	
IOL	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64	ША	
Δt/Δν	Input transition rise or fall rate; outputs enabled		10	ns/V	
T _{amb}	Operating free-air temperature range	-40	+85	°C	

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	5	T _{amb} =	-40°C to -	+85°C	UNIT
			MIN	TYP ¹	MAX	1	
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_I = -18mA$		0.9	-1.2	V	
		$V_{CC} = 2.7 \text{ to } 3.6\text{V}; I_{OH} = -100\mu\text{A}$	V _{CC} -0.2	V _{CC} -0.1		V	
V_{OH}	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -8mA$		2.4	2.5		V
		$V_{CC} = 3V; I_{OH} = -32mA$		2	2.2		V
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.1	0.2	
		V _{CC} = 2.7V; I _{OL} = 24mA			0.3	0.5	1
V_{OL}	Low-level output voltage	V _{CC} = 3V; I _{OL} = 16mA			0.25	0.4	V
		V _{CC} = 3V; I _{OL} = 32mA			0.3	0.5	1
		V _{CC} = 3V; I _{OL} = 64mA			0.4	0.55	1
		$V_{CC} = 0 \text{ or } 3.6V; V_I = 5.5V$			1	10	
l ₁	Input leakage current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Control pins		±0.1	±1	μΑ
η	Impatioakago oarront	$V_{CC} = 3.6V; V_I = V_{CC}$	Data pins ⁴		0.1	1	μ
		$V_{CC} = 3.6V; V_I = 0$	Data pins		-1	-5]
I_{OFF}	Output off current	$V_{CC} = 0V$; V_I or $V_O = 0$ to 4.5V			1	±100	μΑ
	Due Held current A	$V_{CC} = 3V; V_I = 0.8V$		75	150		
I_{HOLD}	Bus Hold current A inputs ^{NO TAG}	$V_{CC} = 3V; V_I = 2.0V$	-75	-150		μΑ	
	1	$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$	±500			<u> </u>	
I_{EX}	Current into an output in the High state when V _O > V _{CC}	$V_{O} = 5.5V; V_{CC} = 3.0V$			60	125	μА
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} = \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = 0.5V$ to V_{CC} ; $V_I = 0.5V$ to V_{CC} ; $V_I = 0.5V$	GND or V _{CC} ;		±1	±100	μА
I _{OZH}	3-State output High current	$V_{CC} = 3.6V; V_{O} = 3.0V$			1	5	μΑ
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V$			-1	- 5	μΑ
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_{I} = GND$ of		0.12	0.19		
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or	r V _{CC} , I _O = 0		3	12	mA
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GN$	ND or V_{CC} , $I_{O} =$		0.12	0.19	
Δl _{CC}	Additional supply current per input pin ²	V_{CC} = 3.0 to 3.6V; One input at V_{CC} -0 Other inputs at V_{CC} or GND	.6V;		0.1	0.2	mA

NOTES:

- All typical values are at T_{amb} = 25°C.
 This is the increase in supply current for each input at V_{CC} -0.6V.
 This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 10% a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C, only.
 Unused pins at V_{CC} or GND

- 5. I_{CCZ} is measured with outputs pulled to V_{CC} or GND.
 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

3.3V Octal inverting buffer (3-State)

74LVT240

AC CHARACTERISTICS

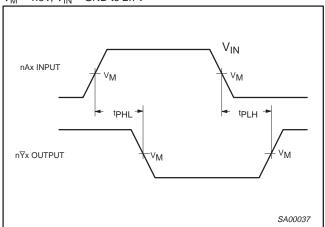
GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500 Ω ; T_{amb} = -40°C to +85°C.

			LIMITS				
SYMBOL	PARAMETER	WAVEFORM	T _{amb} V _C	= -40° C to + $_{\text{C}}$ = +3.3V ± 0 .	85°C 3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH}	Propagation delay nAx to nYx	1	1 1	2.5 2.5	4.3 4.3	5.2 5.0	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1 1	3.7 3.1	5.2 5.2	6.3 6.7	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	2	2 1.6	3.4 3.2	5.6 5.1	6.3 5.6	ns

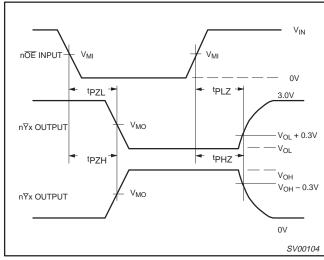
NOTE:

AC WAVEFORMS

 $V_M = 1.5V$, $V_{IN} = GND$ to 2.7V



Waveform 1. Input (nAx) to Output ($n\overline{Y}x$) Propagation Delays



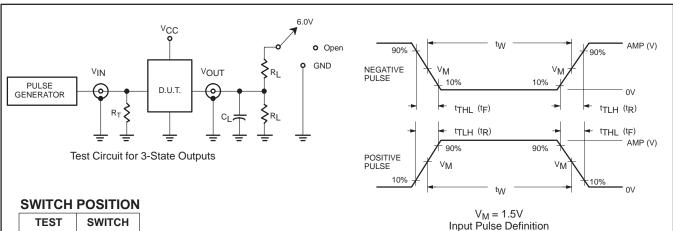
Waveform 2. 3-State Output Enable and Disable Times

^{1.} All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

3.3V Octal inverting buffer (3-State)

74LVT240

TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	6V
t _{PHZ} /t _{PZH}	GND

DEFINITIONS

 R_L = Load resistor; see AC CHARACTERISTICS for value.

 C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T = Termination resistance should be equal to <math>Z_{OUT}$ of pulse generators.

FAMILY	IN	PUT PULSE R	EQUIRE	MENTS	
	Amplitude	Rep. Rate	t _W	t _R	t _F
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

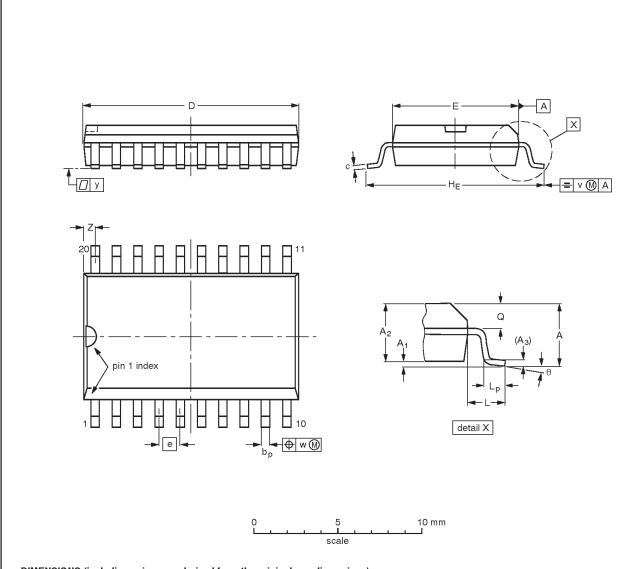
SV00092

3.3V Octal inverting buffer (3-State)

74LVT240

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	٧	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

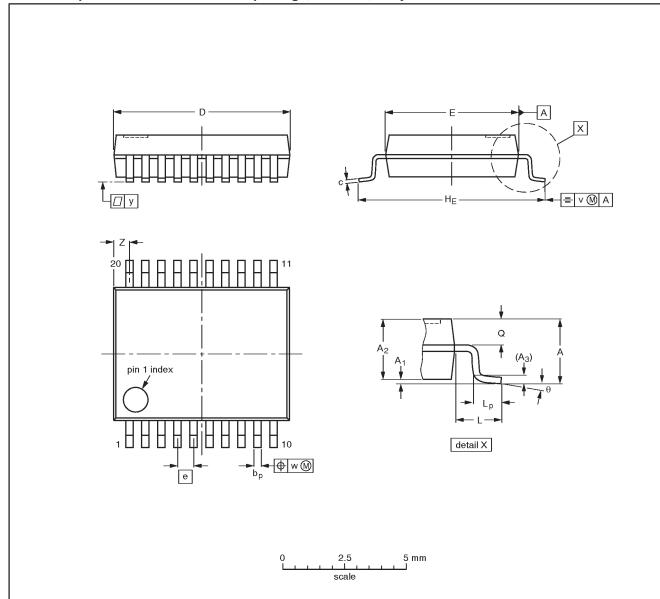
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1930E DATE	
SOT163-1	075E04	MS-013AC			-92-11-17 95-01-24	

3.3V Octal inverting buffer (3-State)

74LVT240

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Ø	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

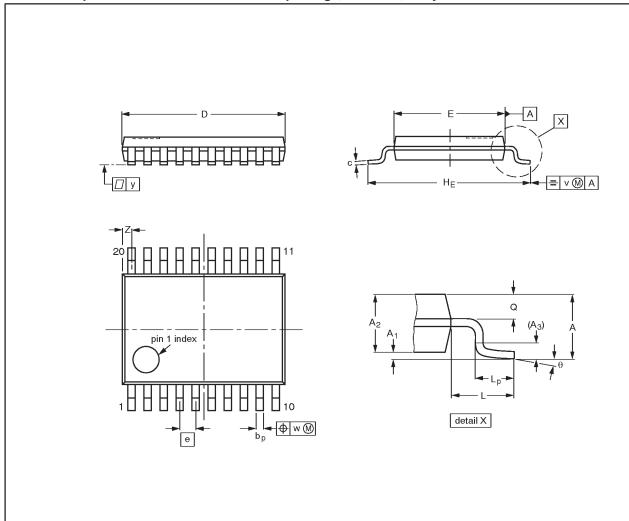
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT339-1		MO-150AE			93-09-08 95-02-04

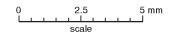
3.3V Octal inverting buffer (3-State)

74LVT240

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	А3	рb	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Œ	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUEDATE
SOT360-1		MO-153AC			-93-06-16- 95-02-04

74LVT240

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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